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# VS-10ETF10FP-M3, VS-10ETF12FP-M3

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# Fast Soft Recovery Rectifier Diode, 10 A



TO-220 FullPAK 2L

| PRIMARY CHARACTERISTICS          |                   |  |  |  |  |
|----------------------------------|-------------------|--|--|--|--|
| I <sub>F(AV)</sub>               | 10 A              |  |  |  |  |
| V <sub>R</sub>                   | 1000 V, 1200 V    |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.33 V            |  |  |  |  |
| I <sub>FSM</sub>                 | 140 A             |  |  |  |  |
| t <sub>rr</sub>                  | 80 ns             |  |  |  |  |
| T <sub>J</sub> max.              | 150 °C            |  |  |  |  |
| Snap factor                      | 0.6               |  |  |  |  |
| Package                          | TO-220 FullPAK 2L |  |  |  |  |
| Circuit configuration            | Single            |  |  |  |  |

### **FEATURES**

- · Glass passivated pellet chip junction
- 150 °C max. operation junction temperature • Designed and qualified according to
- JEDEC<sup>®</sup>-JESD 47



FREE

- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

### DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

| MAJOR RATINGS AND CHARACTERISTICS |                              |             |       |  |  |  |
|-----------------------------------|------------------------------|-------------|-------|--|--|--|
| SYMBOL                            | CHARACTERISTICS              | VALUES      | UNITS |  |  |  |
| V <sub>RRM</sub>                  |                              | 1000, 1200  | V     |  |  |  |
| I <sub>F(AV)</sub>                | Sinusoidal waveform          | 10          | - A   |  |  |  |
| I <sub>FSM</sub>                  |                              | 140         | A     |  |  |  |
| t <sub>rr</sub>                   | 1 A, 100 A/µs                | 80          | ns    |  |  |  |
| V <sub>F</sub>                    | 10 A, T <sub>J</sub> = 25 °C | 1.33        | V     |  |  |  |
| TJ                                |                              | -40 to +150 | °C    |  |  |  |

| VOLTAGE RATINGS |   |   |                                     |  |  |  |
|-----------------|---|---|-------------------------------------|--|--|--|
| PART NUMBER     | V <sub>RRM</sub> , MAXIMUM PEAK<br>REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM<br>NON-REPETITIVE PEAK<br>REVERSE VOLTAGE<br>V | I <sub>RRM</sub><br>AT 150 °C<br>mA |  |  |  |
| VS-10ETF10FP-M3 | 1000  | 1100  | 1                                   |  |  |  |
| VS-10ETF12FP-M3 | 1200  | 1300  | 4                                   |  |  |  |

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| ABSOLUTE MAXIMUM RATINGS                     |                    |  |        |                  |
|--|--------------------|--|--------|------------------|
| PARAMETER                                    | SYMBOL             | TEST CONDITIONS                                    | VALUES | UNITS            |
| Maximum average forward current              | I <sub>F(AV)</sub> | $T_C = 95$ °C, 180° conduction half sine wave      | 10     |                  |
| Maximum peak one cycle                       | I <sub>FSM</sub>   | 10 ms sine pulse, rated $V_{\text{RRM}}$ applied   | 115    | A                |
| non-repetitive surge current                 |                    | 10 ms sine pulse, no voltage reapplied             | 140    |                  |
| Marine 12t fan frain a                       | l <sup>2</sup> t   | 10 ms sine pulse, rated $V_{RRM}$ applied          | 66     | A <sup>2</sup> s |
| Maximum I <sup>2</sup> t for fusing          | 1-1                | 10 ms sine pulse, no voltage reapplied             | 94     | A-S              |
| Maximum I <sup>2</sup> $\sqrt{t}$ for fusing | l²√t               | t = 0.1 to 10 ms, no voltage reapplied 940 $A^{2}$ |        | A²√s             |

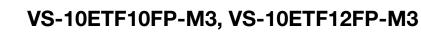
| ELECTRICAL SPECIFICATIONS       |                    |                              |                         |        |       |
|---------------------------------|--------------------|------------------------------|-------------------------|--------|-------|
| PARAMETER                       | SYMBOL             | TEST CONDITIONS              |                         | VALUES | UNITS |
| Maximum forward voltage drop    | V <sub>FM</sub>    | 10 A, T <sub>J</sub> = 25 °C |                         | 1.33   | V     |
| Forward slope resistance        | r <sub>t</sub>     | T <sub>J</sub> = 150 °C      |                         | 22.9   | mΩ    |
| Threshold voltage               | V <sub>F(TO)</sub> |                              |                         | 0.96   | V     |
| Maximum reverse leakage current |                    | $T_J = 25 \text{ °C}$        | 0.1                     | mA     |       |
| Maximum reverse leakage current | IRM                | T <sub>J</sub> = 150 °C      | $V_R$ = rated $V_{RRM}$ | 4      | ШA    |

| RECOVERY CHARACTERISTICS |                 |  |        |       |                                |
|--------------------------|-----------------|--|--------|-------|--------------------------------|
| PARAMETER                | SYMBOL          | TEST CONDITIONS  | VALUES | UNITS | · •                            |
| Reverse recovery time    | t <sub>rr</sub> | L at 10 A  | 310    | ns    | I <sub>FM</sub>                |
| Reverse recovery current | I <sub>rr</sub> | l <sub>F</sub> at 10 A <sub>pk</sub><br>25 Α/μs<br>25 °C | 4.7    | А     |                                |
| Reverse recovery charge  | Q <sub>rr</sub> | 25 0   | 1.05   | μC    | $\frac{\text{dir}}{\text{dt}}$ |
| Snap factor              | S               |  | 0.6    |       |                                |

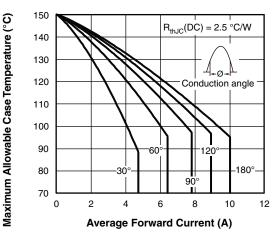
| THERMAL - MECHANICAL SPECIFICATIONS            |         |                                   |                                       |                        |            |
|--|---------|-----------------------------------|---------------------------------------|------------------------|------------|
| PARAMETER                                      |         | SYMBOL                            | TEST CONDITIONS                       | VALUES                 | UNITS      |
| Maximum junction and storage temperature range |         | T <sub>J</sub> , T <sub>Stg</sub> |                                       | -40 to +150            | °C         |
| Maximum thermal resistar junction to case      | nce     | R <sub>thJC</sub>                 | DC operation                          | 2.5                    |            |
| Maximum thermal resistance junction to ambient |         | R <sub>thJA</sub>                 |                                       | 62                     | °C/W       |
| Typical thermal resistance case to heatsink    | ,<br>,  | R <sub>thCS</sub>                 | Mounting surface, smooth, and greased | 0.5                    |            |
| Approximate weight                             |         |                                   |                                       | 2                      | g          |
| Approximate weight                             |         |                                   |                                       | 0.07                   | oz.        |
| minir  |         |                                   |                                       | 6 (5)                  | kgf ⋅ cm   |
| Mounting torque max                            | maximum |                                   |                                       | 12 (10)                | (lbf ⋅ in) |
| Marking device                                 |         |                                   | Case style TO-220 FullPAK 2L          | 10ETF10FP<br>10ETF12FP |            |

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Fig. 1 - Current Rating Characteristics

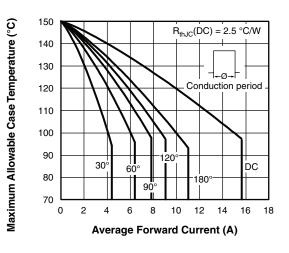


Fig. 2 - Current Rating Characteristics

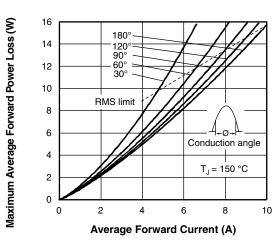


Fig. 3 - Forward Power Loss Characteristics

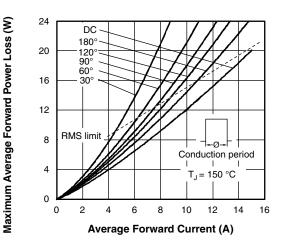
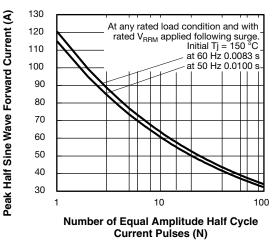
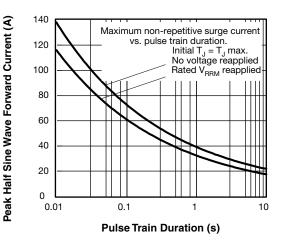
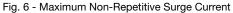


Fig. 4 - Forward Power Loss Characteristics









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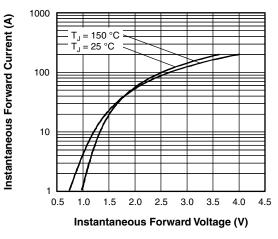


Fig. 7 - Forward Voltage Drop Characteristics

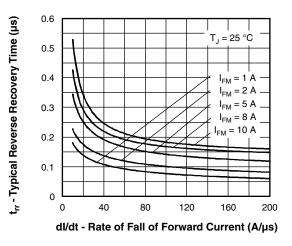


Fig. 8 - Recovery Time Characteristics,  $T_J = 25 \ ^{\circ}C$ 

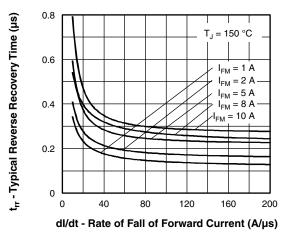


Fig. 9 - Recovery Time Characteristics,  $T_J$  = 150  $^\circ\text{C}$ 

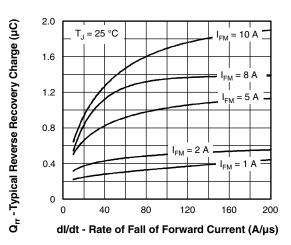
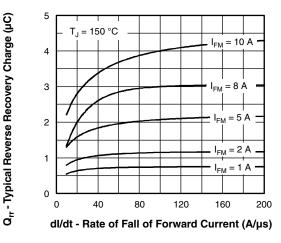
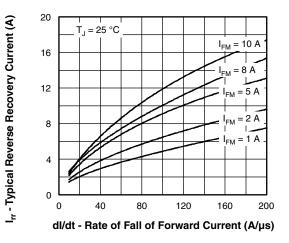
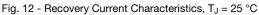


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25 \ ^{\circ}C$ 









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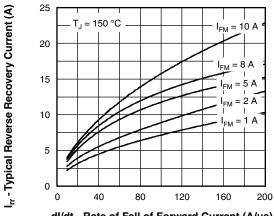
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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics,  $T_J = 150$  °C

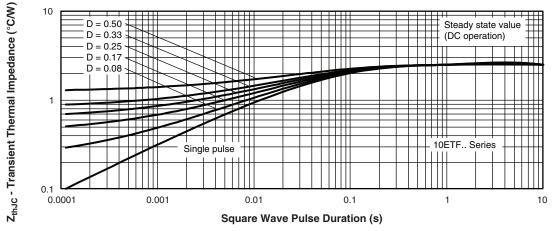


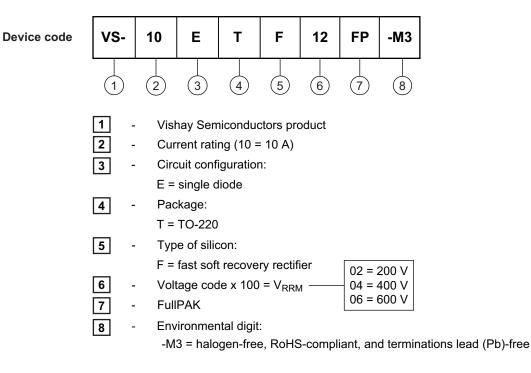
Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics



# VS-10ETF10FP-M3, VS-10ETF12FP-M3

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### **ORDERING INFORMATION TABLE**



| ORDERING INFORMATION (Example) |                  |                        |                          |  |  |
|--------------------------------|------------------|------------------------|--------------------------|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |  |  |
| VS-10ETF10FP-M3                | 50               | 1000                   | Antistatic plastic tubes |  |  |
| VS-10ETF12FP-M3                | 50               | 1000                   | Antistatic plastic tubes |  |  |

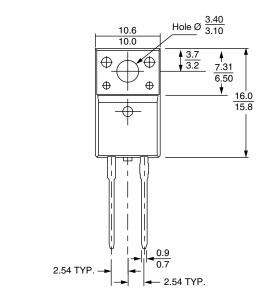
| LINKS TO RELATED DOCUMENTS |                          |  |  |  |
|----------------------------|--------------------------|--|--|--|
| Dimensions                 | www.vishay.com/doc?96157 |  |  |  |
| Part marking information   | www.vishay.com/doc?95392 |  |  |  |

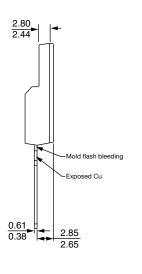


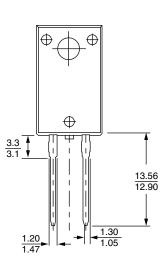
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# 2L TO-220 FullPAK

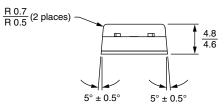
#### **DIMENSIONS** in millimeters







Bottom view





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